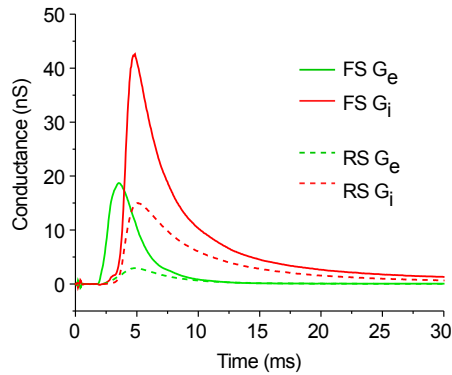


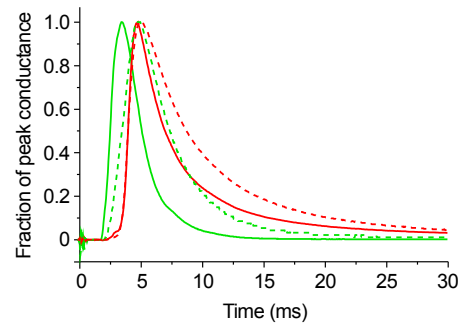
a Intrinsic properties & synaptic reversal potentials:

FS	RS	Common
R_{in} : 81 M Ω	R_{in} : 400 M Ω	E_{rest} : -79 mV
τ_m : 9 ms	τ_m : 28 ms	E_e : 0 mV
C_{in} : 110 pF	C_{in} : 70 pF	E_i : -91 mV

b Synaptic conductances



c Conductance wave shapes



Supplementary Figure 2: Mean intrinsic properties, reversal potentials and synaptic conductances recorded during the experiments and applied in the models. **(a)** The intrinsic properties and synaptic reversal potentials applied in the models for the two cell types. The input resistances (R_{in}), membrane time constants (τ_m), input capacitances (C_{in}), inhibitory synaptic reversal potential (E_i), and resting potential (E_{rest}), were derived from the neurophysiology experiments. The excitatory reversal potential (E_e) was assumed. **(b)** Excitatory and inhibitory synaptic conductances for the FS cells and RS cells used to obtain the modeling results. These were the mean waveforms across cells ($n = 15$ each) from the experiments of Figure 2. **(c)** The same synaptic conductances as in panel b, but normalized to their peaks to facilitate comparison of wave shapes/time-courses.